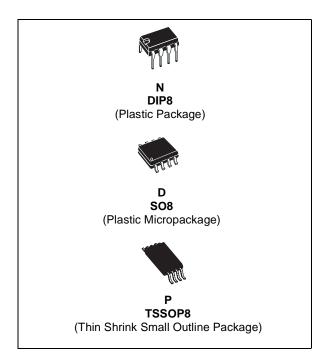


TL082 TL082A - TL082B

GENERAL PURPOSE J-FET DUAL OPERATIONAL AMPLIFIERS

- WIDE COMMON-MODE (UP TO V_{CC}⁺) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT **STAGE**
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE : 16V/µs (typ)



DESCRIPTION

The TL082, TL082A and TL082B are high speed J-FET input dual operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

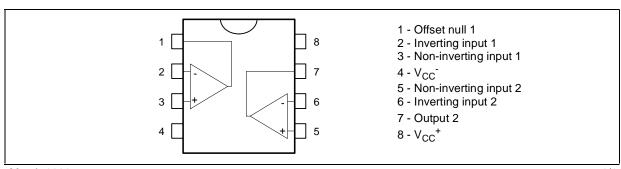
The devices feature high slew rates, low input bias and offset current, and low offset voltage temperature coefficient.

ORDER CODE

Part Number	Temperature	Package N D			
T art ivalliber	Range			Р	
TL082M/AM/BM	-55°C, +125°C	•	•	•	
TL082I/AI/BI	-40°C, +105°C	•	•	•	
TL082C/AC/BC	0°C, +70°C	•	•	•	
Example: TL0820	CD, TL082IN				

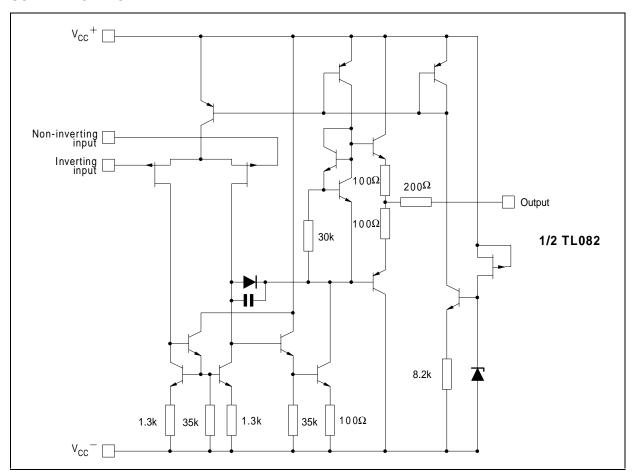
- N = Dual in Line Package (DIP)
 D = Small Outline Package (SO) also available in Tape & Reel (DT)
- P = Thin Shrink Small Outline Package (TSSOP) only available in Tape & Reel (PT)

PIN CONNECTIONS (top view)



March 2002 1/11

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	TL082M, AM, BM	TL082I, AI, BI	TL082C, AC, BC	Unit	
V _{CC}	Supply voltage - note 1)	±18				
V _i	Input Voltage - note ²⁾		±15		V	
V _{id}	Differential Input Voltage - note 3)	±30				
P _{tot}	Power Dissipation	680				
	Output Short-circuit Duration - note 4)	Infinite				
T _{oper}	Operating Free-air Temperature Range	-55 to +125 -40 to +105 0 to +70		°C		
T _{stg}	Storage Temperature Range	-65 to +150				

- All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}.
- 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded

ELECTRICAL CHARACTERISTICS

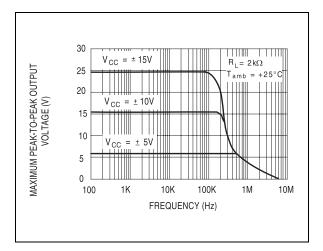
 $V_{CC} = \pm 15V$, $T_{amb} = +25$ °C (unless otherwise specified)

Symbol	Parameter		TL082I,M,AC,AI,AM, BC,BI,BM			, TL082C		
		Min.	Тур.	Max.	Min.	Тур.	Max.	
V _{io}	Input Offset Voltage (R_s = 50 Ω) T_{amb} = +25°C		3 3 1	10 6 3 13 7 5		3	10	mV
DV _{io}	Input Offset Voltage Drift		10			10		μV/°C
I _{io}	Input Offset Current - note $^{1)}$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		5	100 4		5	100 10	pA nA
l _{ib}	Input Bias Current -note 1 $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	200 20		20	400 20	pA nA
A_{vd}	Large Signal Voltage Gain $(R_L = 2k\Omega, V_0 = \pm 10V)$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I _{CC}	Supply Current, no load $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
V_{icm}	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$	80 80	86		70 70	86		dB
I _{os}	Output Short-circuit Current $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$	10 10	40	60 60	10 10	40	60 60	mA
±V _{opp}	$\begin{array}{ll} \text{Output Voltage Swing} \\ T_{amb} = +25^{\circ}\text{C} & \text{RL} = 2k\Omega \\ & \text{RL} = 10k\Omega \\ T_{min} \leq T_{amb} \leq T_{max} & \text{RL} = 2k\Omega \\ & \text{RL} = 10k\Omega \end{array}$	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew Rate (T_{amb} = +25°C) V_{in} = 10V, R_L = 2k Ω , C_L = 100pF, unity gain	8	16		8	16		V/µs
t _r	Rise Time ($T_{amb} = +25^{\circ}C$) $V_{in} = 20mV$, $R_{I} = 2k\Omega$, $C_{I} = 100pF$, unity gain		0.1			0.1		μs
K _{ov}	Overshoot (T_{amb} = +25°C) V_{in} = 20mV, R_L = 2k Ω , C_L = 100pF, unity gain		10			10		%
GBP	Gain Bandwidth Product ($T_{amb} = +25^{\circ}C$) $V_{in} = 10 \text{mV}, R_L = 2 \text{k}\Omega, C_L = 100 \text{pF}, f= 100 \text{kHz}$	2.5	4		2.5	4		MHz
R _i	Input Resistance		10 ¹²			10 ¹²		Ω

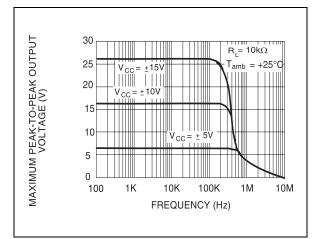
Symbol	Parameter	TL082I,M,AC,AI,AM, BC,BI,BM			TL082C			Unit
		Min.	Тур.	Max.	Min.	Тур.	Max.	
THD	Total Harmonic Distortion (T_{amb} = +25°C), f= 1kHz, R_L = 2k Ω , C_L = 100pF, A_v = 20dB, V_o = 2 V_{pp}		0.01			0.01		%
e _n	Equivalent Input Noise Voltage $R_S = 100\Omega$, $f = 1KHz$		15			15		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
Øm	Phase Margin		45			45		degrees
V ₀₁ /V ₀₂	Channel Separation $A_V = 100$		120			120		dB

^{1.} The input bias currents are junction leakage currents which approximately double for every 10°C increase in the junction temperature.

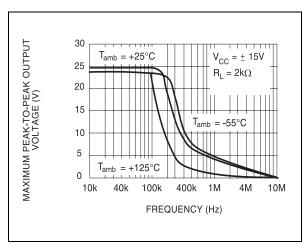
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



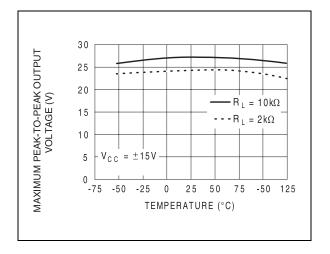
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



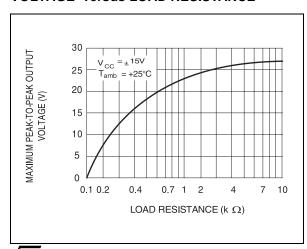
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY



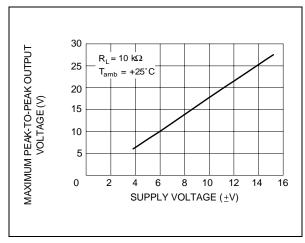
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.



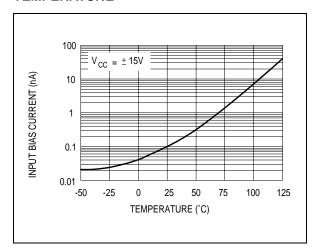
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE



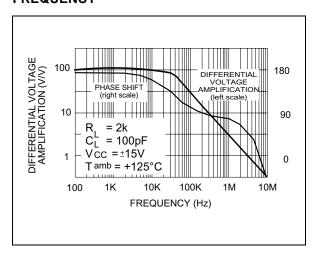
MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE



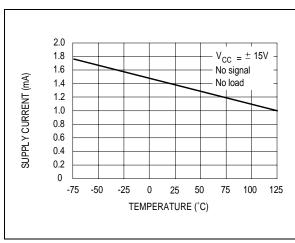
INPUT BIAS CURRENT versus FREE AIR TEMPERATURE



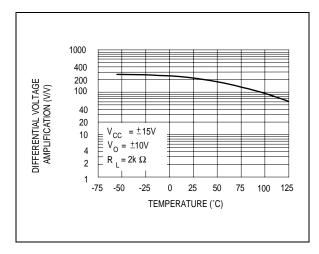
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY



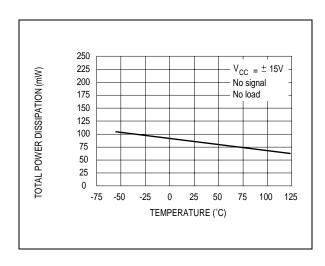
SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE



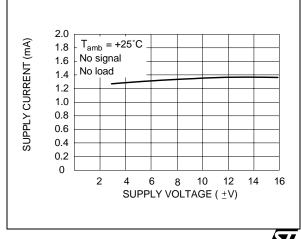
LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION versus FREE AIR TEMP.



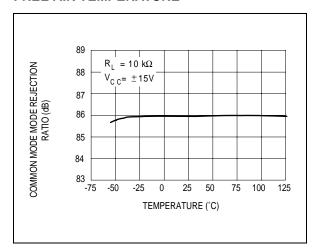
TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE



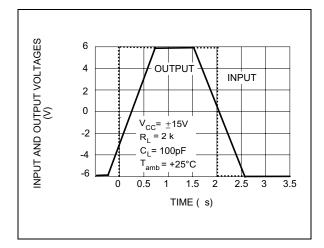
SUPPLY CURRENT PER AMPLIFIER versus SUPPLY VOLTAGE



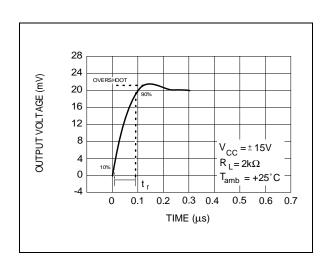
COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE



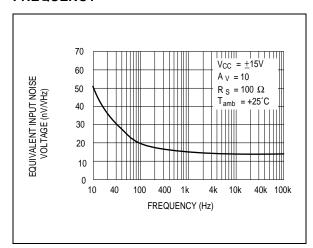
VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE



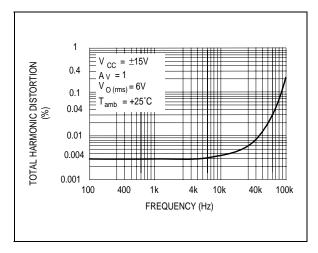
OUTPUT VOLTAGE versus ELAPSED TIME



EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY



TOTAL HARMONIC DISTORTION versus FREQUENCY



PARAMETER MEASUREMENT INFORMATION

Figure 1 : Voltage Follower

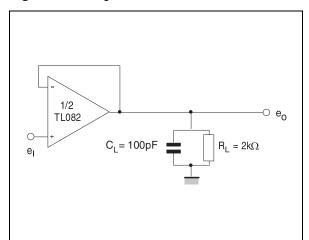
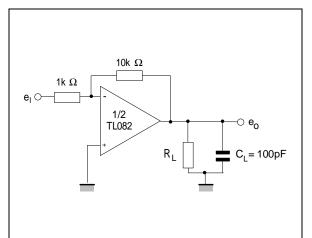
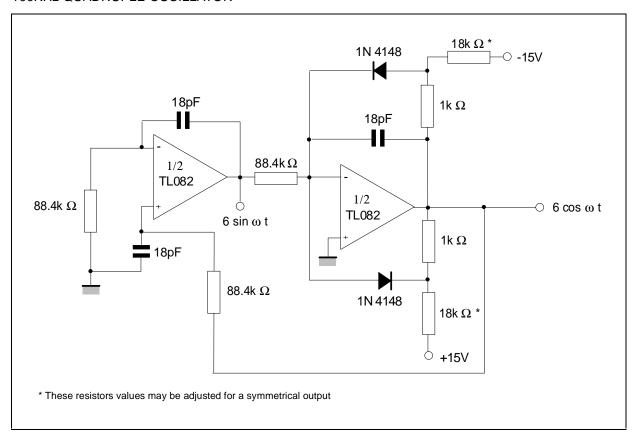


Figure 2 : Gain-of-10 Inverting Amplifier



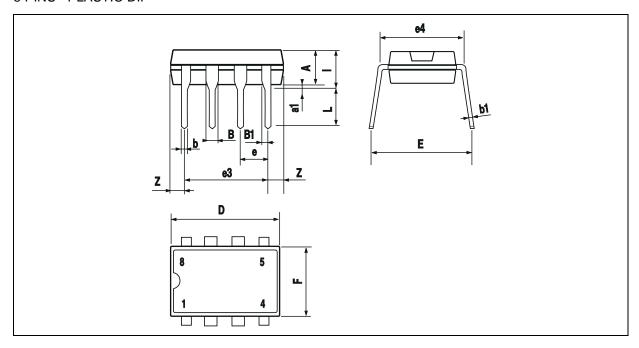
TYPICAL APPLICATIONS

100KHz QUADRUPLE OSCILLATOR



PACKAGE MECHANICAL DATA

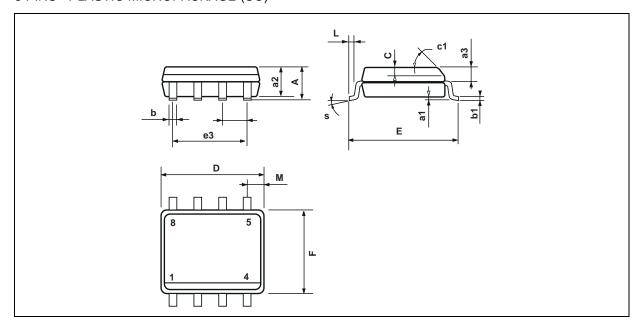
8 PINS - PLASTIC DIP



D'		Millimeters			Inches			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α		3.32			0.131			
a1	0.51			0.020				
В	1.15		1.65	0.045		0.065		
b	0.356		0.55	0.014		0.022		
b1	0.204		0.304	0.008		0.012		
D			10.92			0.430		
Е	7.95		9.75	0.313		0.384		
е		2.54			0.100			
e3		7.62			0.300			
e4		7.62			0.300			
F			6.6			0260		
i			5.08			0.200		
L	3.18		3.81	0.125		0.150		
Z			1.52			0.060		

PACKAGE MECHANICAL DATA

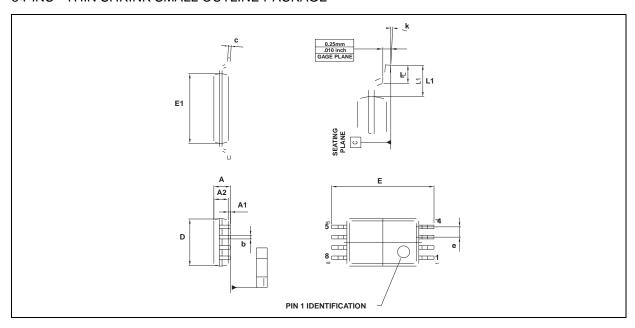
8 PINS - PLASTIC MICROPACKAGE (SO)



Dim	Millimeters			Inches			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
a3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1			45°	(typ.)			
D	4.8		5.0	0.189		0.197	
E	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F	3.8		4.0	0.150		0.157	
L	0.4		1.27	0.016		0.050	
М			0.6			0.024	
S		•	8° (ı	max.)		•	

PACKAGE MECHANICAL DATA

8 PINS - THIN SHRINK SMALL OUTLINE PACKAGE



Dim		Millimeters		Inches			
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α			1.20			0.05	
A1	0.05		0.15	0.01		0.006	
A2	0.80	1.00	1.05	0.031	0.039	0.041	
b	0.19		0.30	0.007		0.15	
С	0.09		0.20	0.003		0.012	
D	2.90	3.00	3.10	0.114	0.118	0.122	
E		6.40			0.252		
E1	4.30	4.40	4.50	0.169	0.173	0.177	
е		0.65			0.025		
k	0°		8°	0°		8°	
I	0.50	0.60	0.75	0.09	0.0236	0.030	
L	0.45	0.600	0.75	0.018	0.024	0.030	
L1		1.000			0.039		

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2001 STMicroelectronics - Printed in Italy - All Rights Reserved STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States

